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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# 2SJ527(L), 2SJ527(S)

## Silicon P Channel MOS FET

REJ03G0877-0300

(Previous: ADE-208-640A)

Rev.3.00 Sep 07, 2005

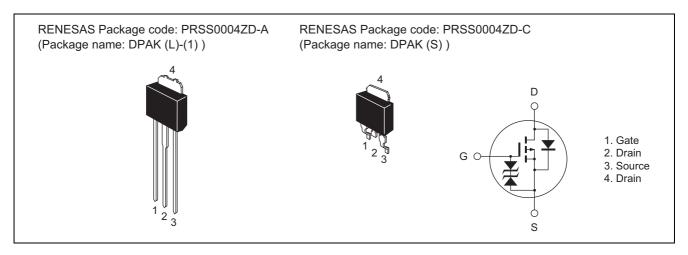
## **Description**

High speed power switching

#### **Features**

- Low on-resistance  $R_{DS (on)} = 0.3 \Omega \text{ typ.}$
- Low drive current
- 4 V gate drive devices
- High speed switching

### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Drain to source voltage	$V_{DSS}$	-60	V
Gate to source voltage	$V_{GSS}$	±20	V
Drain current	I <sub>D</sub>	-5	Α
Drain peak current	I <sub>D (pulse)</sub> Note 1	-20	Α
Body to drain diode reverse drain current	I <sub>DR</sub>	-5	Α
Avalanche current	I <sub>AP</sub> Note 3	-5	Α
Avalanche energy	E <sub>AR</sub> Note 3	2.1	mJ
Channel dissipation	Pch Note 2	20	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

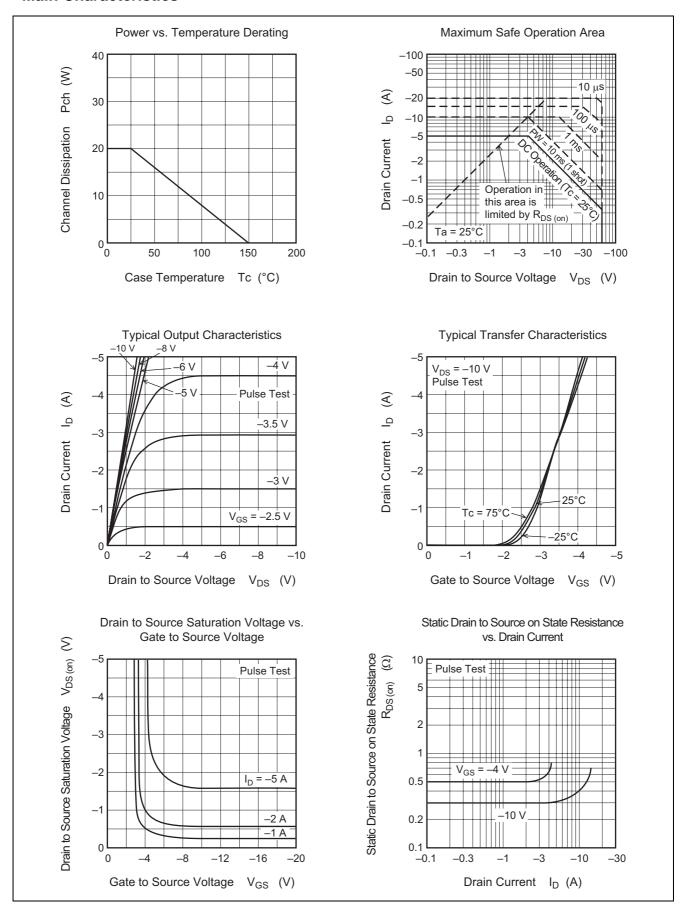
## **Electrical Characteristics**

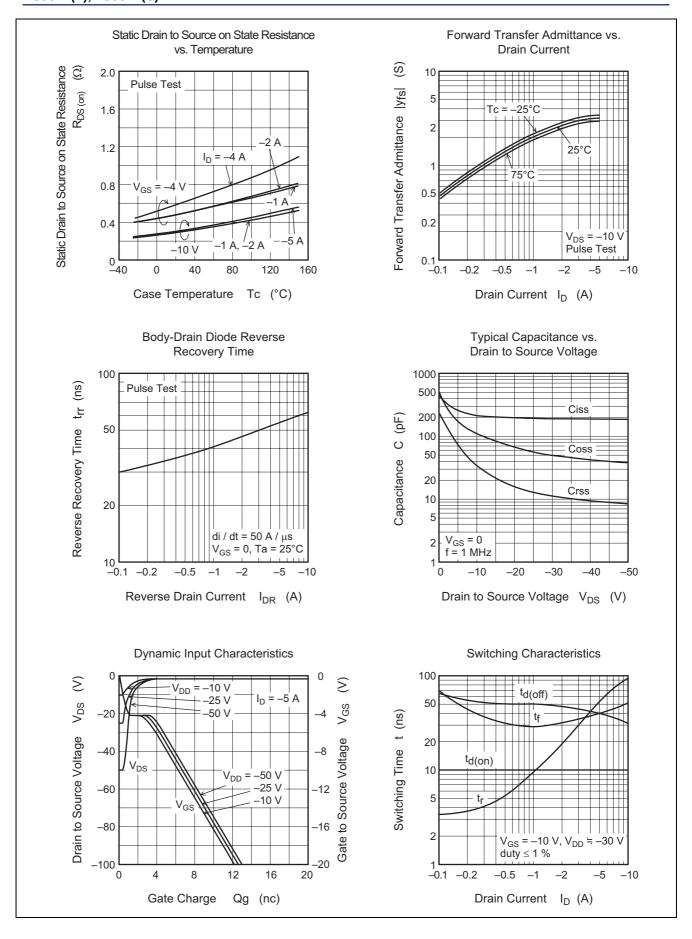
 $(Ta = 25^{\circ}C)$ 

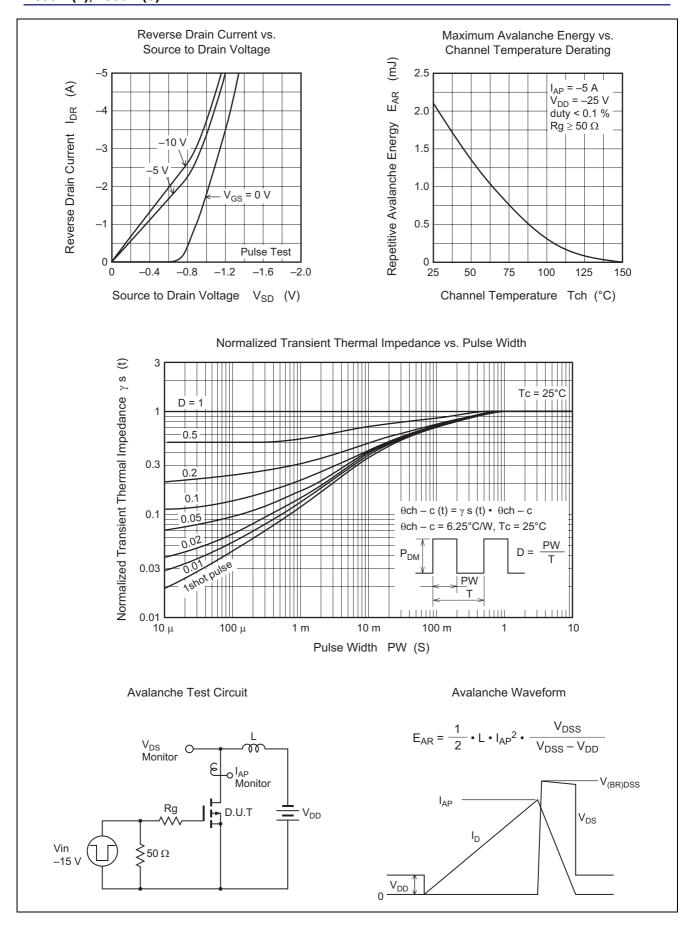
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR) DSS</sub>	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR) GSS</sub>	±20	_	_	V	$I_G = \pm 100 \mu\text{A},  V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	-10	μΑ	$V_{DS} = -60 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	-1.0	_	-2.0	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	R <sub>DS (on)</sub>	_	0.3	0.4	Ω	$I_D = -3 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 4}}$
Static drain to source on state resistance	R <sub>DS (on)</sub>	_	0.5	0.8	Ω	$I_D = -3 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y <sub>fs</sub>	1.8	3	_	S	$I_D = -3 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	220	_	pF	$V_{DS} = -10 \text{ V}$
Output capacitance	Coss	_	110	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	35	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d (on)</sub>	_	10	_	ns	V <sub>GS</sub> = -10 V
Rise time	t <sub>r</sub>	_	30	_	ns	$I_D = -3 A$
Turn-off delay time	t <sub>d (off)</sub>	_	45	_	ns	$R_L = 10 \Omega$
Fall time	t <sub>f</sub>	_	35	_	ns	
Body to drain diode forward voltage	$V_{DF}$	_	-1.35	_	V	$I_F = -5 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t <sub>rr</sub>	_	55	_	ns	$I_F = -5 \text{ A}, V_{GS} = 0$
						di <sub>F</sub> /dt = 50 A/μs

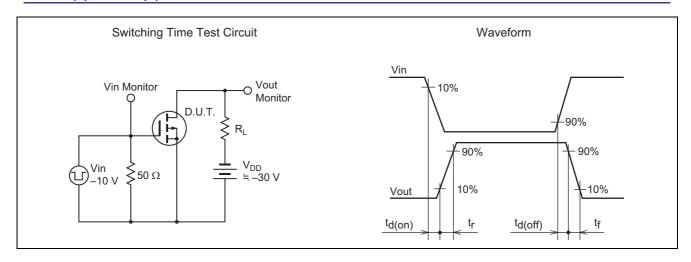
Note: 4. Pulse test

### **Main Characteristics**

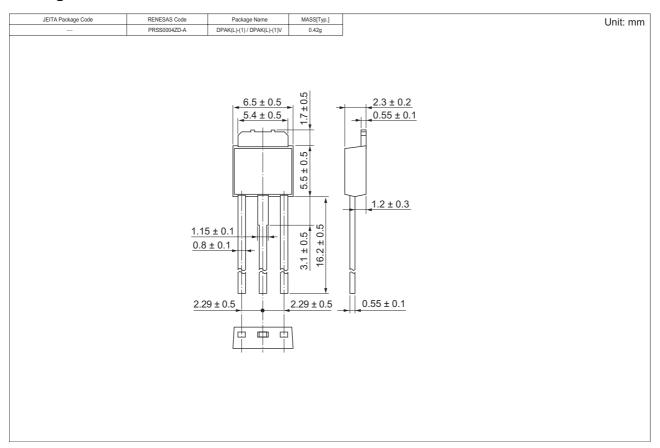


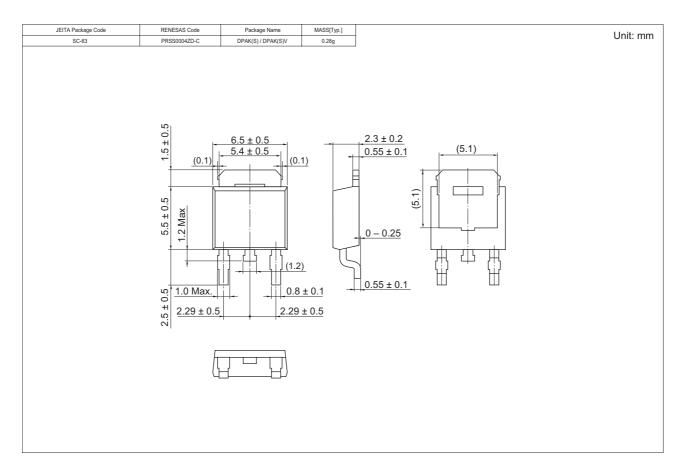






## **Package Dimensions**





## **Ordering Information**

Part Name	Quantity	Shipping Container
2SJ527L-E	3200 pcs	Box (Sack)
2SJ527STL-E	3000 pcs	Taping

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